

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of :
Inventor(s): Sun Woon KIM et al. :
U.S. Patent Application No.: *Not yet assigned* : Group Art Unit: *Not yet assigned*
Filed: *Herewith* :
For: FABRICATION METHOD OF NITRIDE SEMICONDUCTORS AND NITRIDE
SEMICONDUCTOR STRUCTURE FABRICATED THEREBY

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the documents listed on the attached form PTO-1449. It is respectfully requested that the documents be expressly considered during the prosecution of this application, and that the documents be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed within three months of the U.S. filing date OR before the mailing date of a first Office Action on the merits. No certification or fee is required.

The attached references appear in the specification.

Respectfully submitted,

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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.